Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	293	advantag$ with extension with source	US-PGPUB; USPAT	OR	ON	2005/03/03 19:10
L2	4	advantag$ with extension with source with ldd	US-PGPUB; USPAT	OR	ON	2005/03/03 19:07
L3	176	advantag$ with extension with source with drain	US-PGPUB; USPAT	OR	ON	2005/03/03 19:12
L4	1	("6784101").PN.	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:13
L5	0	4 and nitride	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:13
L6	1	("6100153").PN.	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:13
L7	0	6 and nitride	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:26
L8	1	("6281059").PN.	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:26
L9	192	1 and contact	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:26
L10	1	8 and contact	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:28
L11	0	8 and plug	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:26
L12	192	plug and (gate with (silicon adj nitride) with (etch$3 near stop$4))	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:29
L13	222	plug and (gate with (silicon adj nitride) with (etch$3 near stop$4))	US-PGPUB; USPAT	OR	ON	2005/03/03 19:29
L14	203	13 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/03 19:36
L15	1	("6686247").PN.	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:37
L16	1	15 and "209"	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:59
L17	1	("6784101").PN.	US-PGPUB; USPAT	OR	OFF	2005/03/03 19:59
L18	1	17 and thickness	US-PGPUB; USPAT	OR	OFF	2005/03/03 20:31
L19	1	("5273915").PN.	US-PGPUB; USPAT	OR	OFF	2005/03/03 20:31
L20	0	19 and (nitride with spacer)	US-PGPUB; USPAT	OR	OFF	2005/03/03 20:31
L21	1	19 and (nitride with spacer)	US-PGPUB; USPAT	OR	ON	2005/03/03 20:31
S1	2026	((438/238) or (438/381-385)). CCLS.	US-PGPUB; USPAT	OR	OFF	2005/03/03 15:01

S2	947	S1 and resistor	US-PGPUB; USPAT	OR	ON	2005/03/03 15:04
S3	103	S2 and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 21:08
S4	92	S3 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/03 19:29
S5	39	(("4314269") or ("5629544") or ("5811857") or ("6008095") or ("6015993") or ("6232163") or ("6258664") or ("6294834") or ("6358791") or ("20020153549") or ("6475838") or ("6489664") or ("20030030091") or ("6524905") or ("20030080386") or ("6558998") or ("20040026765") or ("4631803") or ("4946799") or ("5447884") or ("5461250") or ("5534713") or ("5714777") or ("5763315") or ("6046487") or ("6059895") or ("6222234") or ("6291321") or ("6387739") or ("20020076899") or ("6413802") or ("6414355") or ("6429061") or ("6448114") or ("20020190284") or ("20030001219") or ("6555839") or ("6621131") or ("6653700")).PN.	US-PGPUB; USPAT	OR	OFF	2005/03/02 13:09
S6	10	S5 and resistor	US-PGPUB; USPAT	OR	ON	2005/03/02 13:10
S7	8	S6 and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 18:50
S8	8	S7 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/02 19:44
S9	92	S4 not S8	US-PGPUB; USPAT	OR	ON	2005/03/02 13:48
S10	268	(jennifer near2 kennedy).xa.	US-PGPUB; USPAT	OR	ON	2005/03/02 13:37
S11	26	S10 and resistor	US-PGPUB; USPAT	OR	ON	2005/03/02 20:23
S12	4	S11 and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 19:44
S13	3	09/944986	US-PGPUB; USPAT	OR	ON	2005/03/02 16:33
S14	1	("6821840").PN.	US-PGPUB; USPAT	OR	OFF	2005/03/02 16:33
S15	1	S14 and (dop$3)	US-PGPUB; USPAT	OR	OFF	2005/03/02 17:33

S16	4	S9 and (buried adj resistor)	US-PGPUB; USPAT	OR	ON	2005/03/02 17:25
S17	1	S14 and (resistor)	US-PGPUB; USPAT	OR	ON	2005/03/02 17:34
S18	105	(YEO-YEE-CHIA HU-CHENMING HU-CHEN-MING)".in"	US-PGPUB; USPAT	OR	ON	2005/03/02 17:35
S19	105	(YEO-YEE-CHIA HU-CHENMING HU-CHEN-MING).in.	US-PGPUB; USPAT	OR	ON	2005/03/02 17:35
S20	10	S19 and (resistor)	US-PGPUB; USPAT	OR	ON	2005/03/02 18:42
S21	130	((high adj k) (high adj dielectric))with (resistor)	US-PGPUB; USPAT	OR	ON	2005/03/02 21:08
S22	123	S21 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/02 21:08
S23	23	S22 and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 18:44
S24	22	S23 not S9	US-PGPUB; USPAT	OR	ON	2005/03/02 18:44
S25	64	(resistor adj body) and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 18:51
S26	2	((resistor adj body) with (dop$3) with substrate) and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 19:05
S27	2	(("6558998") or ("6518610")).PN.	US-PGPUB; USPAT	OR	OFF	2005/03/02 19:44
S28	1254	(438/381-385).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/03/02 19:44
S29	1201	S28 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/02 19:52
S30	128	S29 and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 20:53
S31	249	(257/538).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/03/02 19:51
S32	242	S31 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/02 19:52
S33	19	S32 and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 19:52
S34	0	(taiwan adj semiconductor) and resisitor and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 20:24

S35	50	(taiwan adj semiconductor) and resistor and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 20:24
S36	64	S30 and resistor	US-PGPUB; USPAT	OR	ON	2005/03/02 20:53
S37	40436	resistor and (soi or (silicon adj on adj insula$4) or box or (buried adj oxide))	US-PGPUB; USPAT	OR	ON	2005/03/02 21:12
S38	37315	S37 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/02 21:13
S39	23	S38 and ((high adj k) (high adj dielectric)) with (resistor)	US-PGPUB; USPAT	OR	ON	2005/03/02 21:13
S40	16013	S38 and (substrate semiconductor)	US-PGPUB; USPAT	OR	ON	2005/03/02 21:12
S41	15513	S40 not (po adj box)	US-PGPUB; USPAT	OR	ON	2005/03/02 21:12
S42	2805	resistor and (soi or (silicon adj on adj insula$4))	US-PGPUB; USPAT	OR	ON	2005/03/02 21:12
S43	2480	S42 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/02 21:14
S44	2	S43 and ((high adj k) (high adj dielectric)) with (resistor)	US-PGPUB; USPAT	OR	ON	2005/03/02 21:14
S45	1172	((high adj k) (high adj dielectric)) with (gate adj dielectric)	US-PGPUB; USPAT	OR	ON	2005/03/02 21:16
S46	1049	S45 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/02 21:16
S47	607	((high adj k) (high adj dielectric)) with (gate adj dielectric) with oxide	US-PGPUB; USPAT	OR	ON	2005/03/02 21:19
S48	539	S47 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/02 21:23
S49	35	((high adj k) (high adj dielectric)) with (gate adj dielectric) with (oxide with interfacial)	US-PGPUB; USPAT	OR	ON	2005/03/03 15:22
S50	104	S48 and (etch$3 adj stop$3)	US-PGPUB; USPAT	OR	ON	2005/03/02 21:23
S51	1	("20040026762").PN.	US-PGPUB; USPAT	OR	OFF	2005/03/03 15:01
S53	0	S51 and (etch$3 adj stop$3)	US-PGPUB; USPAT	OR	OFF	2005/03/03 15:02
S54	0	S51 and (etch$3 near2 stop$3)	US-PGPUB; USPAT	OR	OFF	2005/03/03 15:02
S55	0	S51 and (etch$3 near2 stop$4)	US-PGPUB; USPAT	OR	OFF	2005/03/03 15:03

S56	1	("6720621").PN.	US-PGPUB; USPAT	OR	OFF	2005/03/03 15:03
S57	1	S56 and "7"	US-PGPUB; USPAT	OR	OFF	2005/03/03 15:04
S58	1	("6833299").PN.	US-PGPUB; USPAT	OR	OFF	2005/03/03 15:04
S59	0	S58 and resistor	US-PGPUB; USPAT	OR	ON	2005/03/03 15:04
S60	149	(etch$3 near stop$4) with (silicon adj nitride) with gate with contact	US-PGPUB; USPAT	OR	ON	2005/03/03 15:22
S62	138	S60 not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/03 15:24
S63	0	(thin adj film adj resisitor) not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/03 15:25
S64	3267	(thin adj film adj resisitor) not (@ad>"20030808" or @rlad>"20030808")	US-PGPUB; USPAT	OR	ON	2005/03/03 15:25
S65	86	S64 and soi	US-PGPUB; USPAT	OR	ON	2005/03/03 19:06